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CONTENTS

Organizers	<i>iii</i>
International Programme Committee	<i>iv</i>
Foreword	<i>v</i>
Contents	<i>vi</i>
Sensors & Microsystems 1	
Energy Harvesting Using Thermoelectric Microgenerators: A Critical Analysis	1
G. Wachutka	
Influence of temperature on the sensitivity of the AlGaIn/GaN C HEMT based piezoelectric pressure sensor	5
J. Dzuba, G. Vanko, I. Ryger, M. Vallo, V. Kutis, T. Lalinsky	
Temperature sensor on flexible substrate patterned by laser ablation	9
M. D. Dankoco , E. Benevent, E. Bergeret, L. Gallais, M. Bendahan	
Invited Talk 1	
Organic semiconductor based field-effect transistors	13
M. Weis	
Organic Electronics	
Analysis on carrier trapping mechanism in organic diodes by charge modulation spectroscopy and electric field optical second harmonic generation measurement	21
E. Lim, M. Bok, D. Taguchi, M. Iwamoto	
Probing and Modelling of Carrier Transport in Organic Devices by Optical Second Harmonic Generation	25
M. Iwamoto, T. Manaka, D. Taguchi	
Technology of conductive polymer PEDOT:PSS films	29
J. Nevrelá, M. Micjan, M. Novota, S. Flickyngerova, J. Kovac Jr, M. Pavuk, P. Juhasz, J. Jakabovic, M. Weis	

Poster Session 1 Technology & Devices	
SiC graphene FET with polydimethylglutarimide as a gate dielectric layer J. Nahlik, Z. Soban, J. Voves, V. Jurka, P. Vasek	33
Electrical characterization of diamond films deposited in nitrogen and oxygen containing gas mixture M. Mikolasek, M. Vojs, M. Varga, O. Babchenko, T. Izak, M. Marton, A. Kromka, L. Harmatha	37
Radiation Hardness of 4H-SiC Structures A. Kosa, J. Benkowska, L. Stuchlikova, D. Buc, F. Dubecky, L. Harmatha	41
Electrical Properties of Semi-Insulating GaAs Irradiated with 5 MeV Electrons P. Bohacek, B. Zatko, A. Sagatova, P. Hybler, M. Sekacova	45
M/SI-GaAs/M diode: Role of the metal contact in electrical transport, α-particle and photon detection F. Dubecky, B. Zatko, G. Vanko, P. Hubik, J. Osvald, D. Kindl, E. Gombia, J. Kovac, A. Sagatova, V. Necas	49
Transition from a-Si:H to Si₃N₄ in thin films deposited by PECVD technology from silane diluted with nitrogen P. Sutta, P. Calta, J. Mullerova, M. Netrvalova, J. Savkova, V. Vavrunkova	53
Development issue in mushroom-like profile fabrication in EBL double step exposure method K. Indykiewicz, B. Paszkiewicz, T. Szymanski, R. Paszkiewicz	57
Electron irradiation effects on the spectrometric characteristics of GaAs detectors A. Sagatova, B. Zatko, K. Sedlackova, V. Necas, M. Fulop	61
Analysis of detection properties of particle detectors based on 4H-SiC high quality epitaxial layer B. Zatko, F. Dubecky, K. Sedlackova, A. Sagatova, P. Bohacek, M. Sekacova, V. Necas	65
Determination of elastic properties of surface layers and coatings M. Sevcik, M. Husak	69
Precise etching of AlGaIn/GaN HEMT structures with Cl₂/BCl₃/Ar plasma J. Gryglewicz, R. Paszkiewicz, W. Macherzynski, A. Stafiniak, M. Wosko	73
Application of real time in-situ interferometry for the observation of GaN/Si MOVPE growth process T. Szymanski, M. Wosko, B. Paszkiewicz, K. Indykiewicz, R. Paszkiewicz	77
Different buffer approaches for AlGaIn/GaN heterostructures epitaxy on Si(111) substrates M. Wosko, B. Paszkiewicz, T. Szymanski, R. Paszkiewicz	81
III-nitride nano-LEDs for single photon lithography St. Trellenkamp, M. Mikulics, A. Winden, Y. C. Arango, J. Moers, M. Marso, D. Grutzmacher, H. Hardtdegen	85
Novel Double-Level-Gate Technology A. Fox, M. Mikulics, H. Hardtdegen, St. Trellenkamp, Y. C. Arango, D. Grutzmacher, Z. Sofer, D. Gregusova, J. Novak, P. Kordos, M. Marso	89
Ferroelectric polymer films for flexible memory devices M. Micjan, J. Nevrela, M. Novota, S. Flickyngerova, P. Juhasz, J. Uhrik, J. Jakabovic, M. Weis	93
New phenanthrene-based organic semiconductor material for electronic devices M. Novota, M. Micjan, J. Nevrela, S. Flickyngerova, P. Juhasz, R. Misicak, M. Putala, J. Jakabovic, M. Weis	97

Invited Talk 2	
Novel GaN-based transistors using polarization engineering	101
A. Vescan, H. Hahn, B. Reuters, H. Kalisch	
GaN Based Structures & Devices 1	
Design of GaN Trig-Gate HEMTs	105
M. Alsharef, R. Granzner, E. Ture, R. Quay, J. Racko, J. Breza, F. Schwierz	
Modeling and characterization of power InAlN/GaN HEMTs supported by 3-D electrothermal simulation	109
M. Molnar, D. Donoval, A. Chvala, J. Marek, P. Pribytny	
AlN/GaN/AlN double heterostructures with thin AlN top barriers	113
Ch. Zervos, A. Bairamis, A. Adikimenakis, A. Kostopoulos, M. Kayampaki, K. Tsagaraki, G. Konstantidis, A. Georgakilas	
GaN Based Structures & Devices 2	
GaN HEMTs on Si Substrate with High Cutoff Frequency	117
W. Jatal, K. Tonisch, U. Baumann, F. Schwierz, J. Pezoldt	
Impact of the buffer structure on trapping characteristics of normally-off p-GaN/AlGaIn/GaN HEMTs for power switching applications	121
M. Tapajna, L. Valik, P. Kotara, R. Zhytnytska, F. Brunner, O. Hilt, E. B. Treidel, J. Wuerfl, J. Kuzmik	
Investigation of defects in GaN HFET structures by electroluminescence	125
J. Priesol, A. Satka, L. Sladek, M. Bernat, D. Donoval	
Different polarities of InN (0001) heterostructures on Si (111) substrates	129
A. Bairamis, A. Adikimenakis, A. O. Ajagunna, Th. Kehagias, G. P. Dimitrakopoulos, J. Kioseoglou, Ph. Komninou, Ch. Zervos, J. Kuzmik, A. Georgakilas	
Gate leakage reduction of AlGaIn/GaN MOS-HFETs with HfO₂ prepared by ALD	133
R. Stoklas, D. Gregusova, M. Blaho, K. Cico, K. Frohlich, J. Novak, P. Kordos	
Invited Talk 3	
GaN Transistor Reliability and Instabilities	137
M. Uren, M. Kuball	
GaN Based Structures & Devices 3	
Time Resolved EBIC Study of InAlN/GaN HFETs	145
A. Satka, J. Priesol, M. Bernat, D. Donoval, J. Kovac, D.W.E. Allsopp, J. Kuzmik	
Analysis of Time Dependent Current Collapse in AlGaIn/GaN HEMTs	149
R. Maeta, H. Tokuda, M. Kuzuhara	
Modelling and Optimization of GaN Capped HEMTs	153
S. Faramehr, P. Igic, K. Kalna	
Influence of structure geometry and bulk traps on switching transients of InAlN/GaN HEMT	157
J. Marek, A. Satka, D. Donoval, M. Molnar, J. Priesol, A. Chvala, P. Pribytny	
Invited Talk 4	
Energy efficient computing with tunnel FETs	161
A. Ionescu	
Advanced Devices	
Simulative Study on Physical Modelling of Submicrometer Highly-strained In_{0.8}Ga_{0.2}As/AlAs Resonant Tunnelling Diode	169
W. M. Jubadi, M. A. Zawawi, M. Missous	

Statistical Analysis of Active and Passive RF Devices	173
M. Pak, A. E. Yarimbiyik, G. Dundar, F. Fernandez	
Poster Session 2 Characterization & Sensors	
Special-purpose oscillators	177
J. Foit, M. Husak	
Model of Coupled Defect Level Recombination with Participation of Multiphonons	181
J. Racko, R. Granzner, P. Benko, M. Mikolasek, L. Harmatha, M. Kittler, F. Schwierz, J. Breza	
Defects in Schottky Diodes Based on AlGaIn/GaN Heterostructures	185
L. Stuchlikova, A. Kosa, J. Benkovska, P. Benko, L. Harmatha, J. Kovac	
DLTS Study of Electrically Active Defects in Triple Quantum Well InGaAsN/GaAs Heterostructures	189
A. Kosa, L. Stuchlikova, P. Benko, J. Jakus, L. Harmatha, J. Kovac, B. Sciana, W. Dawidowski, D. Radziewicz, D. Pucicki, M. Tlaczala	
Degradation process in AlGaIn/GaN HEMTs under high drain-bias off-state stress	193
M. Florovic, J. Kovac, P. Benko, J. Skriniarova, P. Kordos, D. Donoval	
Characterization of Gas Sensor with Polyaniline Film	197
J. Kroutil, A. Laposka, J. Nahlik, A. Boura, M. Husak	
Simulation of Distributed MOEMS for Smart Environments	201
V. Shakhnov, L. Zinchenko, I. Kosolapov	
Quality Water Analyzer	205
M. Husak, A. Laposka, P. Kulha, P. Nepras	
Translator with Magnetic Levitation	209
F. Puci, M. Husak	
Precise beat frequency evaluation circuit for multi-oscillators QCM gas detectors	213
A. Boura, J. Kroutil	
Frequency dependent capacitance of insulator GaN/AlGaIn/GaN heterostructure	217
J. Osvald, G. Vanko, K. Frohlich	
Energy harvesting in 3D	221
V. Janicek	
Calculation of accurate channel spacing of an Arrayed Waveguide Grating optical multiplexer/demultiplexer applying position method	225
E. Hodzic, D. Seyringer, F. Uherek, J. Chovan, A. Kuzma	
Design of low loss 1x64 Y-branch splitter having symmetric splitting ratio and small footprint	229
C. Burtscher, D. Seyringer, F. Uherek, J. Chovan, A. Kuzma	
Methods for Lifetime Characterization of Concentric Circuit Boards	233
J. Formanek, J. Jakovenko	
Analysis of Interfering Signals in Structures of Integrated Circuits	237
J. Novak, J. Foit	
Modeling of geometrically scalable integrated finger diodes	241
V. Kosel, F. Roger, K. Molnar, W. Posch, E. Seebacher	

Invited Talk 5	
The characterization and use of nanostructured films in sensing applications O. N. De Oliveira Jr.	245
Sensors & Microsystems 2	
Sensitivity and long term stability of γ-Fe₂O₃ and CoFe₂O₄ nanoparticle gas sensors for NO₂, CO and acetone sensing - a comparative study S. Luby, M. Jergel, M. Benkovicova, P. Siffalovic, J. Ivanco, K. Vegso, E. Majkova, R. Rella, M. G. Manera, S. Capone, I. Vavra	247
Complex measurement of human physiology using designed miniature wireless sensors E. Vavrinsky, D. Moskalova, J. Mihalov, M. Donoval, M. Daricek, V. Stopjakova	251
Using of laser ablation technique in the processing technology of GaN/SiC based MEMS for extreme conditions J. Zehetner, G. Vanko, P. Choleva, J. Dzuba, I. Ryger, T. Lalinsky	255
Characterization & Modeling	
AlGaN/GaN micromembranes with diamond coating for high electron mobility transistors operated at high temperatures G. Vanko, M. Vojs, T. Izak, P. Potocky, P. Choleva, M. Marton, I. Ryger, J. Dzuba, T. Lalinsky	259
Modelling Heating Effects due to Current Crowding in ZnO Nanowires with End-Bonded Metal Contacts O. Kryvchenkova, K. Kalna, R. J. Cobley	263
Material and electrical properties of N-polar (GaN)/InN surfaces K. Cico, A. Adikimenakis, M. Micusik, S. Hascik, A. Georgakilas, J. Kuzmik	267
Templates for highly ordered SiGe-QD arrays for single photon detection J. Moers, N. P. Stepina, St. Trelenkamp, D. Grutzmacher	271
Application of TCAD in a Development of a Fully Complementary Vertical PNP IC Technology for High Performance Analog Applications R. Spetik, S. Kapsia, J. Pjencak	275
Total internal reflection ellipsometry in the investigation of phenomena at surfaces and interfaces for biosensing J. Chlpik, K. Bombarova, J. Cirak	279
Invited Talk 6	
Photonic and plasmonic structures for applications in solar cells M. Zeman, A. Ingenito, H. Tan, D.N.P. Linssen, R. Santbergen, A. Smets, O. Isabella	283
Solar cells	
Spectral Analysis of In_xGa_{1-x}N/GaN Quantum Well Structures for III-nitride based Solar Cells D. O'Mahony, P. J. Parbrook, B. Corbett, J. Kovac, J. Kovac jr., M. Florovic, A. Vincze	287
Determination of defect states in P3HT material for solar cell application P. Juhasz, L. Stuchlikova, M. Micjan, L. Harmatha, J. Jakabovic, M. Weis	291
Opto-electrical approaches for high efficiency and ultra-thin c-Si solar cells A. Ingenito, O. Isabella, M. Zeman	295
Planar waveguide based structures for integrated optics on PDMS D. Jandura, D. Pudis, S. Slabeyciusova, J. Durisova	299

Photovoltaics - LED's	
Influence of Geometry on the Directionality of Light Emission of Nano-rod Array Vertical Light Emitting Diodes	303
S.A. Fox, S. Lis, S.E.J. O'Kane, D.W.E. Allsopp, J. Sarma	
Investigation of Optical Stability Issues with Embedded Semiconductor Quantum Dots used as Colour Conversion Material in LED Lighting Applications	307
D. Schmidmayr, J. Zehetner, P. Amann	
InGaN nano-LEDs for energy saving optoelectronics	311
M. Marso, M. Mikulics, A. Winden, Y. C. Arango, A. Schafer, Z. Sofer, D. Grutzmacher, H. Hardtdegen	
Detailed optical and electrical characterisation of green – orange InGaN/GaN LEDs grown by MOVPE	315
K. Cavanagh, C. Liu, T. Martin, M. A. Hopkins, S. Sivaraya, D. W. E. Allsopp	
LEDs with polydimethylsiloxane 2D PhC membrane in the surface	319
D. Pudis, L. Suslik, R. Nolte, P. Schaaf, J. Kovac, P. Gaso	
SMART System Co-design - Special session of 7 FP project SMAC	
Homogenous Simulation: the Effective Integration Solution for Smart Systems	323
F. Fummi, M. Lora, D. Trachanis, J. V. Hese, S. Vinco	
Advanced methodology for fast 3-D TCAD electrothermal simulation of power devices	327
A. Chvala, D. Donoval, J. Marek, P. Pribytny, M. Molnar	
A MEMS Design Methodology for Model-Order Reduction, based on High-order Parametric Elements	331
A. Sanginario, G. Schropfer, S. Zerbini, M. Ekwinska, R. Houlihan, D. Demarchi	
Design and simulation of an integrated optical CMOS heart rate sensor	335
D. He, C. Liu, D. Trachanis, J.V. Hese, D. Drogoudis, F. Fummi, F. Stefanni, V. Guarnieri, S.P. Morgan, B.R. Hayes-Gill	
TCAD Simulation Methodology for 3-D Electro-Physical and Optical Analysis	339
P. Pribytny, M. Molnar, A. Chvala, J. Marek, M. Mikolasek, D. Donoval,	
Author index	343